

# TC74HC4518AP/AF TC74HC4520AP/AF

## TC74HC4518AP/AF DUAL BCD COUNTER TC74HC4520AP/AF DUAL 4-BIT BINARY COUNTER

The TC74HC4518A and TC74HC4520A are high speed CMOS DUAL BCD/4-BIT BINARY COUNTER fabricated with silicon gate C<sup>2</sup>MOS technology.

They achieve the high speed operation similar to equivalent LSTTL while maintaining the CMOS low power dissipation.

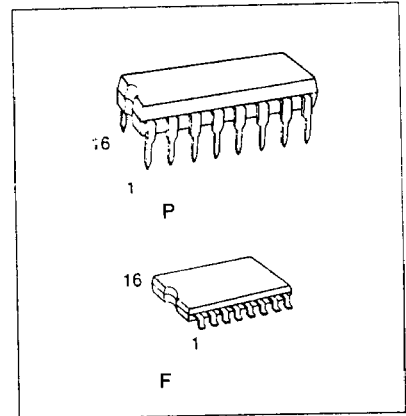
Since the TC74HC4518A and the TC74HC4520A each contain two independent counter circuits in one package, counting or frequency division of two BCD digits or eight binary bits can be achieved with one device. The counters are reset to "0" (Q<sub>0</sub>~Q<sub>3</sub> low) by setting the CLEAR input high regardless of the other inputs.

Counting occurs on the positive going (rising edge) transition of CLOCK if CE is high or the negative going (falling edge) transition of CLOCK if CE is low.

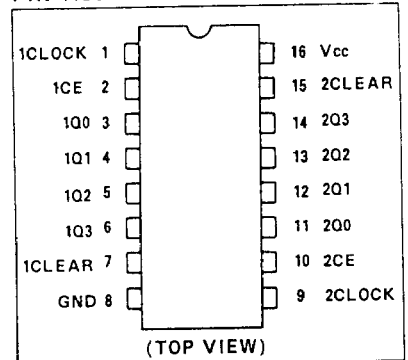
All inputs are equipped with protection circuits against static discharge or transient excess voltage.

### FEATURES:

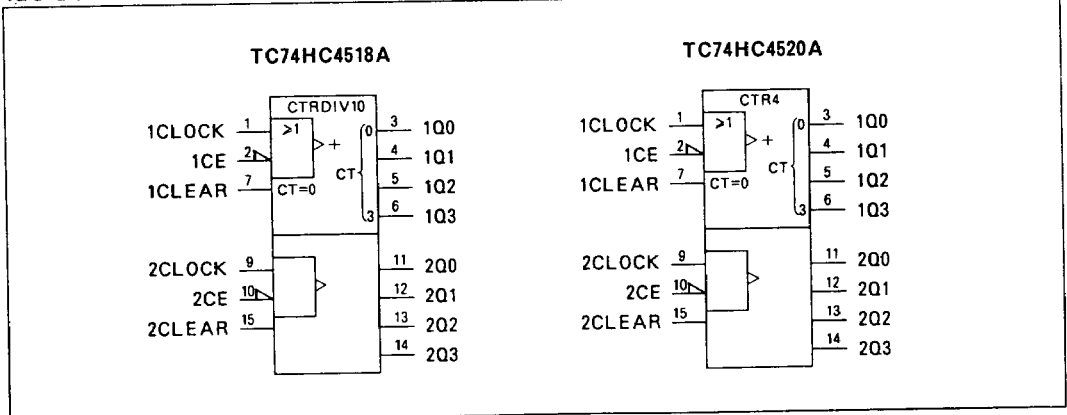
- High Speed .....  $f_{MAX}=55\text{MHz(Typ.)at } V_{CC}=5\text{V}$
- Low Power Dissipation .....  $I_{CC}=4\mu\text{A(Max.)at } T_a=25^\circ\text{C}$
- High Noise Immunity .....  $V_{NIH}=V_{NIL}=28\% V_{CC}(\text{Min.})$
- Output Drive Capability ..... 10 LSTTL Loads
- Symmetrical Output Impedance .....  $|I_{OH}|=I_{OL}=4\text{mA}(\text{Min.})$
- Balanced Propagation Delays .....  $t_{PLH}\approx t_{PHL}$
- Wide Operating Voltage Range .....  $V_{CC}(\text{opr})=2\text{V}\sim 6\text{V}$
- Pin and Function Compatible with 4518B/4520B



### PIN ASSIGNMENT









### IEC LOGIC SYMBOL



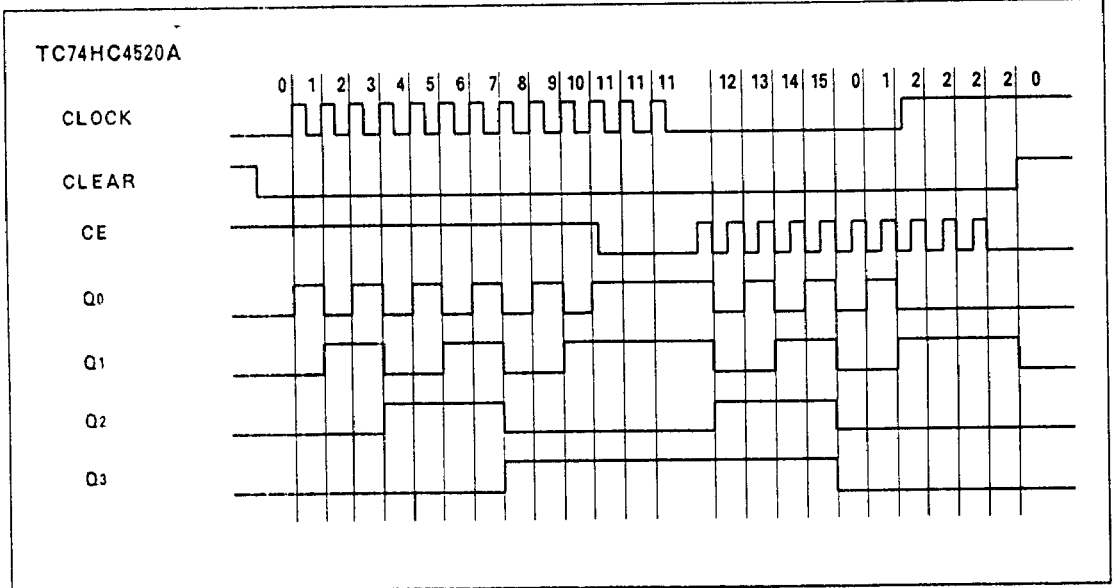
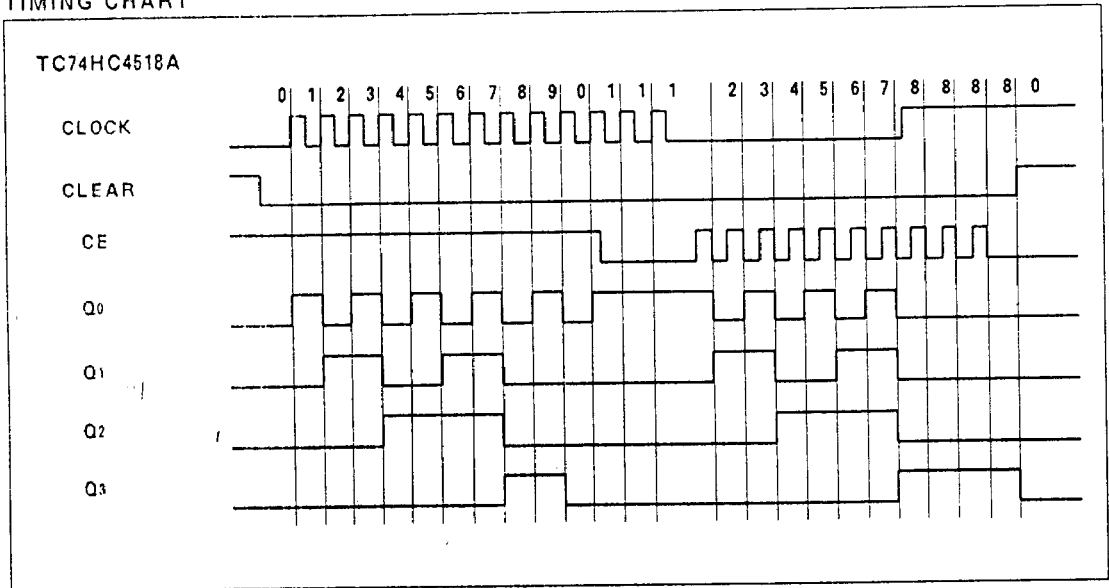
TC74HC4518AP/AF 4520AP/AF-1

TRUTH TABLE

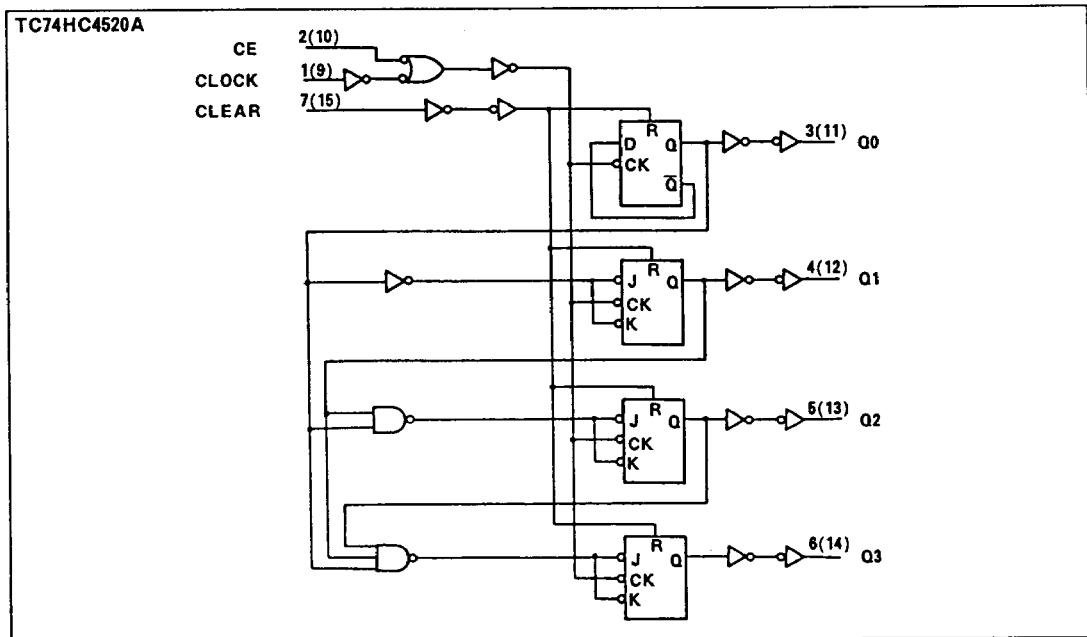
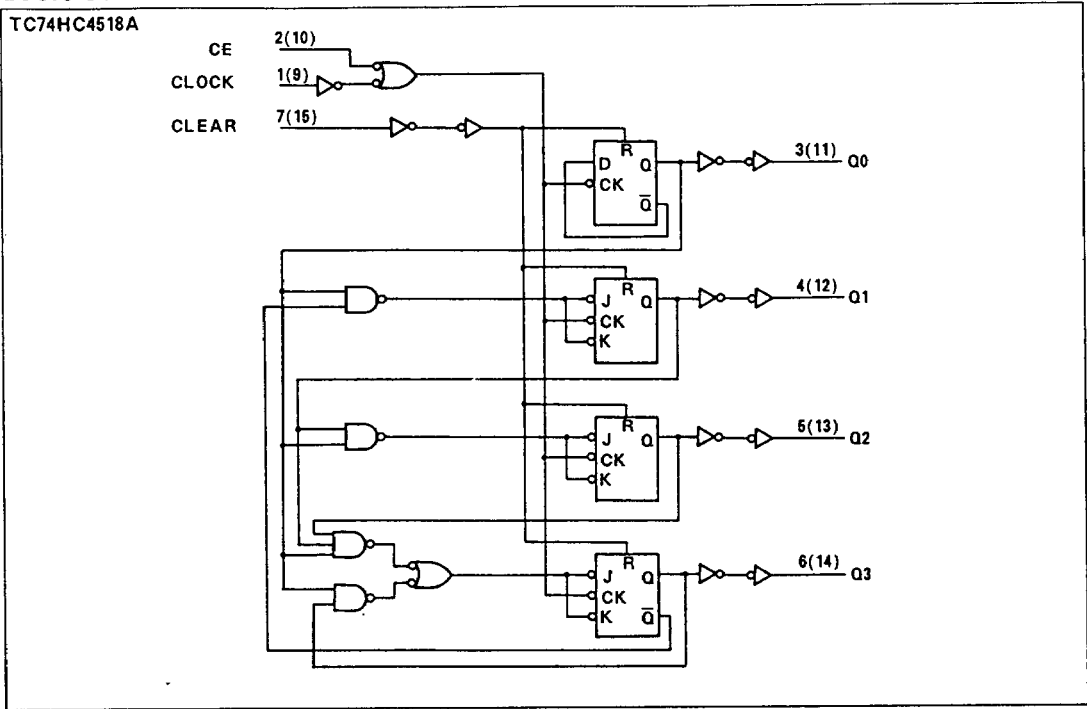
INPUT			FUNCTION
CLOCK	CE	CLEAR	
	H	L	INCREMENT COUNTER
L		L	INCREMENT COUNTER
	X	L	NO CHANGE
X		L	NO CHANGE
	L	L	NO CHANGE
H		L	NO CHANGE
X	X	H	Q0 THRU Q3=L

X: Don't Care

TIMING CHART



LOGIC DIAGRAM



TC74HC4518AP/AF 4520AP/AF-4

### ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage Range	$V_{CC}$	-0.5 ~ 7	V
DC Input Voltage	$V_{IN}$	-0.5 ~ $V_{CC}$ +0.5	V
DC Output Voltage	$V_{OUT}$	-0.5 ~ $V_{CC}$ +0.5	V
Input Diode Current	$I_{IK}$	±20	mA
Output Diode Current	$I_{OK}$	±20	mA
DC Output Current	$I_{OUT}$	±25	mA
DC $V_{CC}$ /Ground Current	$I_{CC}$	±50	mA
Power Dissipation	$P_D$	500(DIP)*/180(SOIC)	mW
Storage Temperature	$T_{stg}$	-65 ~ 150	°C
Lead Temperature 10sec	$T_L$	300	°C

\*500mW in the range of  $T_a = -40^\circ\text{C} \sim 65^\circ\text{C}$ . From  $T_a = 65^\circ\text{C}$  to  $85^\circ\text{C}$  a derating factor of  $-10\text{mW}/^\circ\text{C}$  shall be applied until 300mW.

### RECOMMENDED OPERATING CONDITIONS

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage	$V_{CC}$	2 ~ 6	V
Input Voltage	$V_{IN}$	0 ~ $V_{CC}$	V
Output Voltage	$V_{OUT}$	0 ~ $V_{CC}$	V
Operating Temperature	$T_{opr}$	-40 ~ 85	°C
Input Rise and Fall Time	$t_r, t_f$	0 ~ 1000 ( $V_{CC}=2.0\text{V}$ )	ns
		0 ~ 500 ( $V_{CC}=4.5\text{V}$ )	
		0 ~ 400 ( $V_{CC}=6.0\text{V}$ )	

### DC ELECTRICAL CHARACTERISTICS

PARAMETER	SYMBOL	TEST CONDITION	$T_a = 25^\circ\text{C}$				$T_a = -40 \sim 85^\circ\text{C}$		UNIT	
			$V_{CC}$	MIN.	TYP.	MAX.	MIN.	MAX.		
High-Level Input Voltage	$V_{IH}$		2.0	1.5	-	-	1.5	-	V	
			4.5	3.15	-	-	3.15	-		
			6.0	4.2	-	-	4.2	-		
Low-Level Input Voltage	$V_{IL}$		2.0	-	-	0.5	-	0.5	V	
			4.5	-	-	1.35	-	1.35		
			6.0	-	-	1.8	-	1.8		
High-Level Output Voltage	$V_{OH}$	$V_{IN} = V_{IH} \text{ or } V_{IL}$	$I_{OH} = -20 \mu\text{A}$	2.0	1.9	2.0	-	1.9	-	V
				4.5	4.4	4.5	-	4.4	-	
				6.0	5.9	6.0	-	5.9	-	
				4.5	4.18	4.31	-	4.13	-	
Low-Level Output Voltage	$V_{OL}$	$V_{IN} = V_{IH} \text{ or } V_{IL}$	$I_{OL} = 20 \mu\text{A}$	2.0	-	0.0	0.1	-	0.1	V
				4.5	-	0.0	0.1	-	0.1	
				6.0	-	0.0	0.1	-	0.1	
				4.5	-	0.17	0.26	-	0.33	
Input Leakage Current	$I_{IN}$	$V_{IN} = V_{CC} \text{ or } \text{GND}$	6.0	-	-	±0.1	-	±1.0	$\mu\text{A}$	
			6.0	-	-	4.0	-	40.0		
Quiescent Supply Current	$I_{CC}$	$V_{IN} = V_{CC} \text{ or } \text{GND}$	6.0	-	-	4.0	-	40.0	$\mu\text{A}$	

**TIMING REQUIREMENTS(Input  $t_r=t_f=6ns$ )**

PARAMETER	SYMBOL	TEST CONDITION	Ta=25°C			Ta=-40~85°C	UNIT
			V <sub>CC</sub>	TYP.	LIMIT	LIMIT	
Minimum Pulse Width (CK, CE)	$t_{W(H)}$ $t_{W(L)}$		2.0	-	75	95	ns
			4.5	-	15	19	
			6.0	-	13	16	
Minimum Pulse Width (CLEAR)	$t_{W(H)}$		2.0	-	75	95	
			4.5	-	15	19	
			6.0	-	13	16	
Minimum Removal Time	$t_{rem}$		2.0	-	50	60	
			4.5	-	10	12	
			6.0	-	9	11	
Clock Frequency	f		2.0	-	6	4	MHz
			4.5	-	30	24	
			6.0	-	35	28	

**AC ELECTRICAL CHARACTERISTICS(C<sub>L</sub>=15pF, V<sub>CC</sub>=5V, Ta=25°C)**

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Output Transition Time	$t_{TLH}$ $t_{THL}$		-	4	8	ns
Propagation Delay Time (CK, CE-Qn)	$t_{PLH}$ $t_{PHL}$		-	17	27	
Propagation Delay Time (CLEAR-Qn)	$t_{PHL}$		-	15	25	
Maximum Clock Frequency	f <sub>MAX</sub>		33	55	-	MHz

**AC ELECTRICAL CHARACTERISTICS(C<sub>L</sub>=50pF, Input  $t_r=t_f=6ns$ )**

PARAMETER	SYMBOL	TEST CONDITION	Ta=25°C			Ta=-40~85°C		UNIT	
			V <sub>CC</sub>	MIN.	TYP.	MAX.	MIN.		MAX.
Output Transition Time	$t_{TLH}$ $t_{THL}$		2.0	-	30	75	-	95	ns
			4.5	-	8	15	-	19	
			6.0	-	7	13	-	16	
Propagation Delay Time (CK, CE-Qn)	$t_{PLH}$ $t_{PHL}$		2.0	-	72	160	-	200	
			4.5	-	22	32	-	40	
			6.0	-	18	27	-	34	
Propagation Delay Time (CLEAR-Qn)	$t_{PHL}$		2.0	-	65	150	-	190	
			4.5	-	20	30	-	38	
			6.0	-	16	26	-	33	
Maximum Clock Frequency	f <sub>MAX</sub>		2.0	6	23	-	4	-	MHz
			4.5	30	51	-	24	-	
			6.0	35	60	-	28	-	
Input Capacitance	C <sub>IN</sub>		-	5	10	-	10	pF	
Power Dissipation Capacitance	C <sub>PD(1)</sub>	TC74HC4518A	-	38	-	-	-		
		TC74HC4520A	-	32	-	-	-		

Note(1) C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

$$I_{CC \text{ opd}} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC} / 2 (\text{per circuit})$$

**TC74HC4518AP/AF 4520AP/AF-6**

**850**